
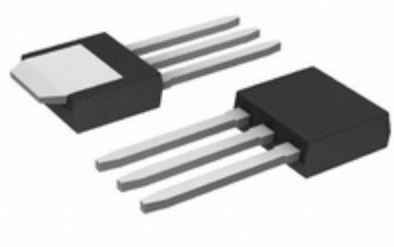


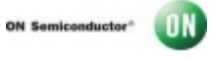
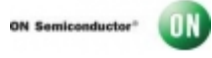
	<p>NTD40N03R-1G</p>
	<p>Hersteller-Teilenummer: NTD40N03R-1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 25V 7.8A IPAK</p> <p>Datenblätter:  NTD40N03R-1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 10900 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD40N03R-1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 25V 7.8A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	10900 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	1.5W (Ta), 50W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	7.8A (Ta), 32A (Tc)
Rds On (Max) @ Id, Vgs	16.5 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	5.78nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	584pF @ 20V
Verpackung	Tube


















































NTD40N03R-1G ist neu im Original, Suche NTD40N03R-1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD40N03R-1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD40N03R-1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD40N03RT4 AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 7.8A DPAK</p>	 <p>NTD40N03R ON NTD40N03R ON</p>	 <p>NTD40N03RT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 7.8A DPAK</p>	 <p>NTD40N03R-1 ON NTD40N03R-1 ON</p>
 <p>NTD40N03G AMI Semiconductor / ON Semiconductor NTD40N03G ON</p>	 <p>NTD40N05 AMI Semiconductor / ON Semiconductor NTD40N05 ON</p>	 <p>NTD40N03RG AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 7.8A DPAK</p>	 <p>NTD4302 AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 8.4A DPAK</p>

heiße Teile

Mehr

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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